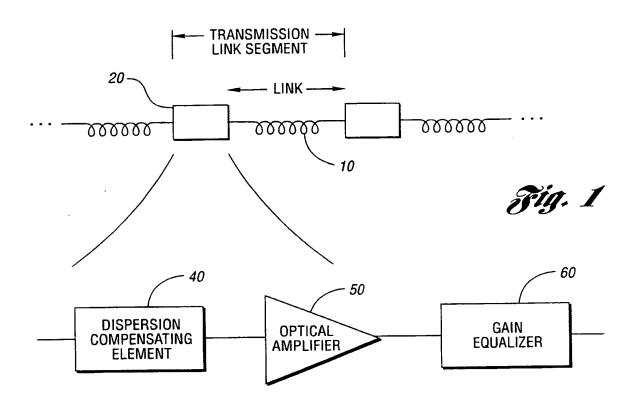
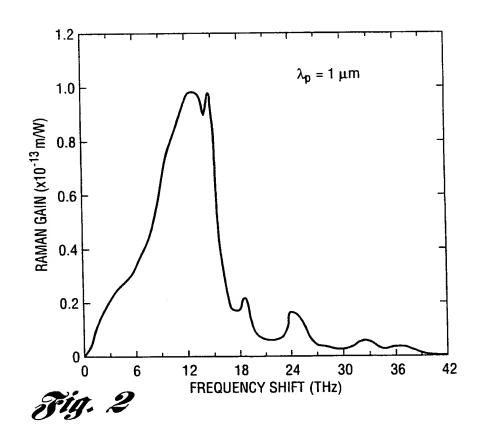
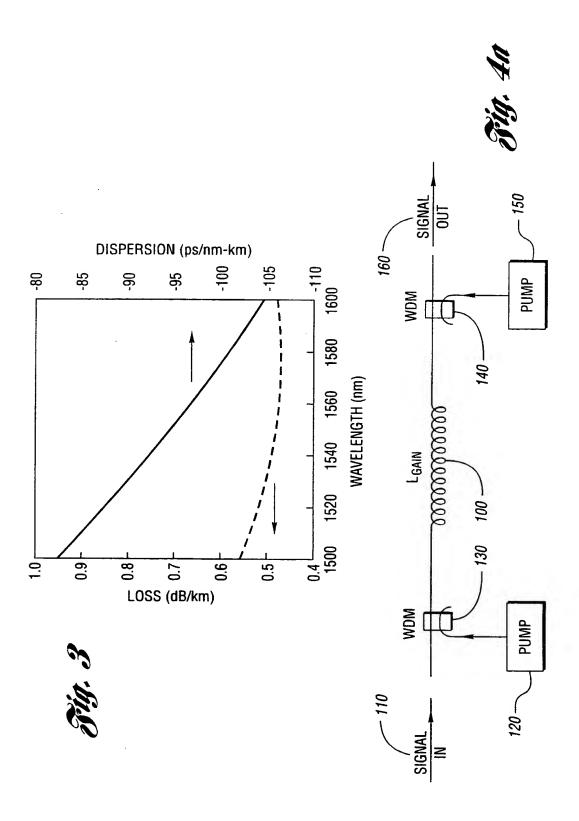
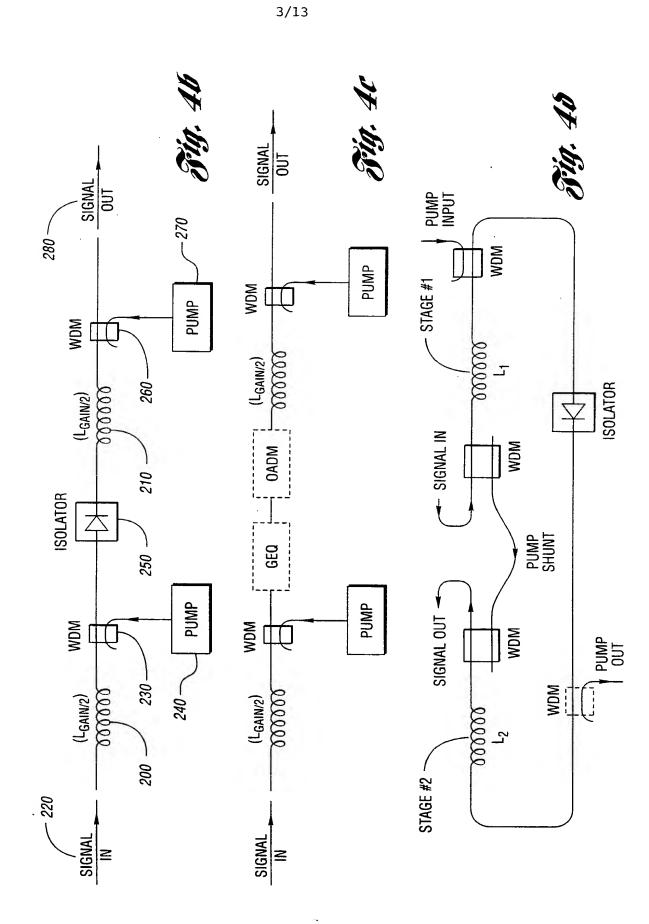
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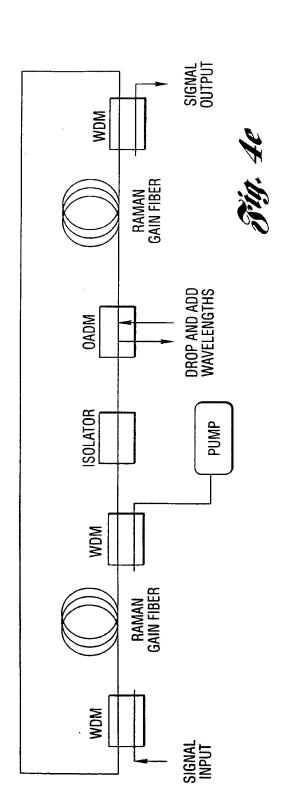


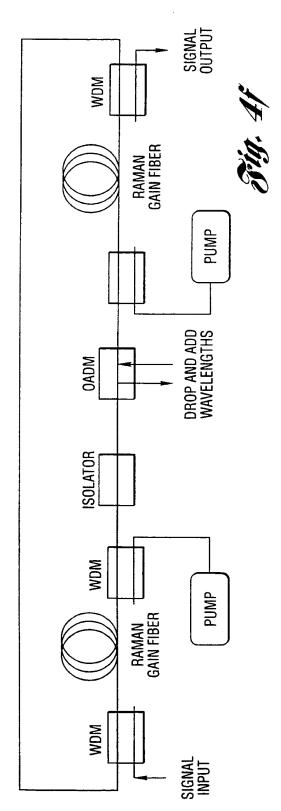


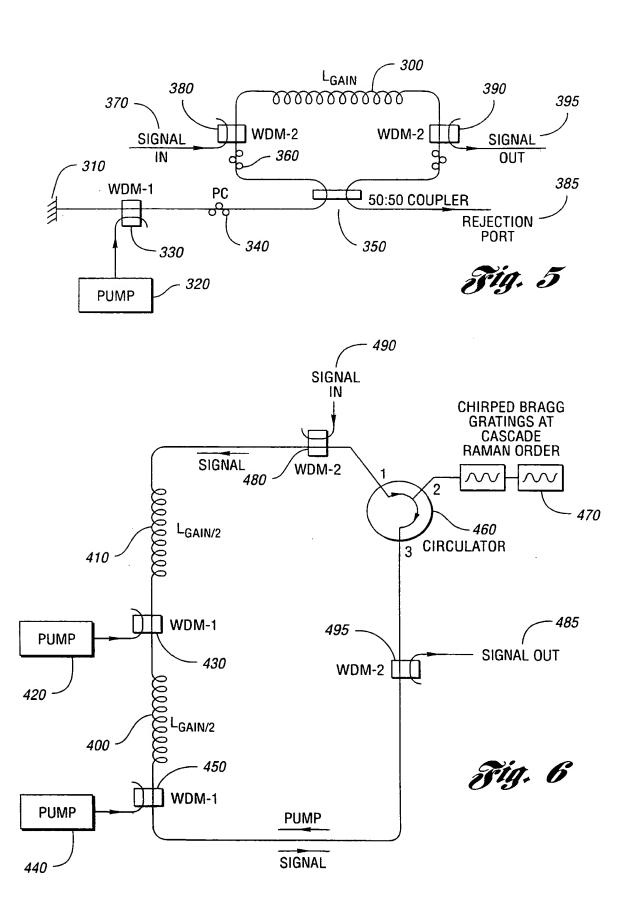




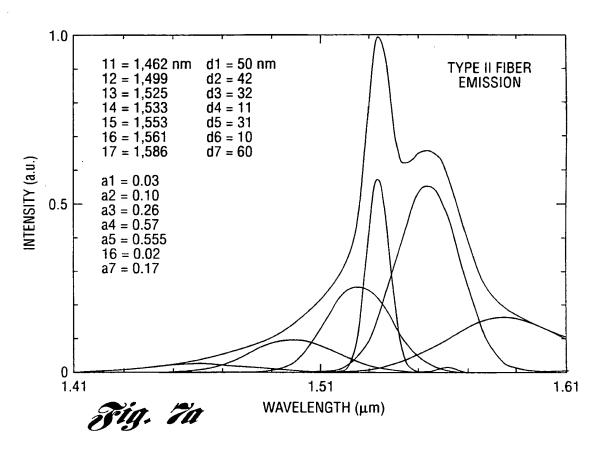


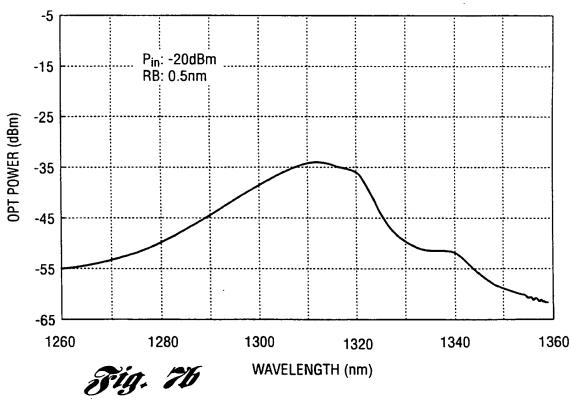




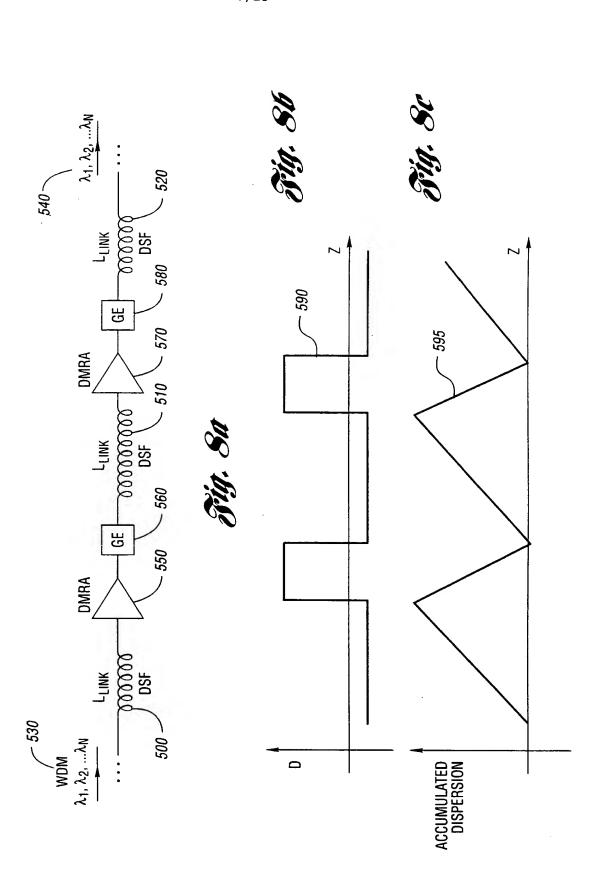


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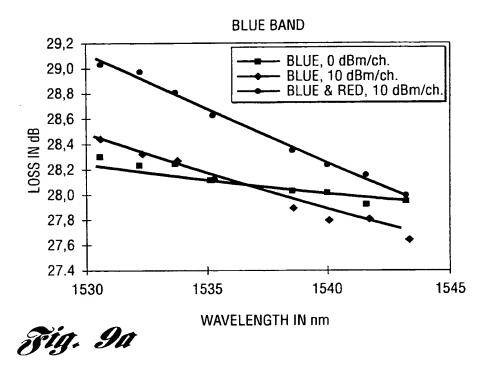


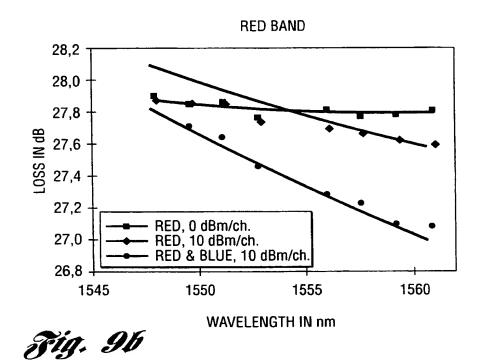


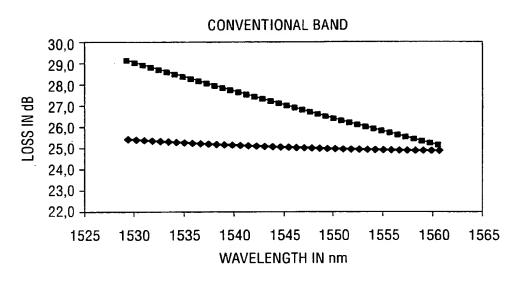
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PCT/US99/13551







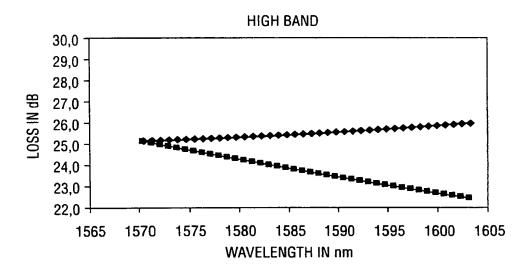
No. ch./dir. :40 Input power :+6 dBm/ch. Conv. band :1529.6 - 1560.6 nm Span Length :100 km

:1570.4 - 1603.2 nm Linear loss High band Ch. spacing :100GHz

:25 dB Mode field area:80 µm² Raman coeff. :4.4 x 10⁻¹⁴ m/W

Fig. 10a





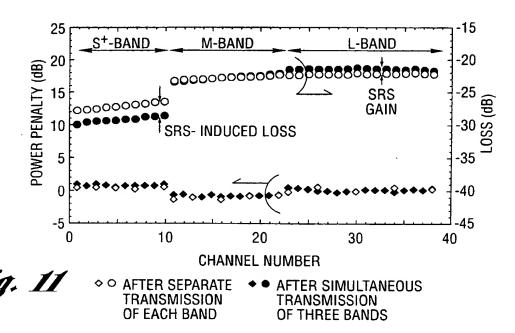
No. ch./dir. :40 . Input power :+6 dBm/ch. Conv. band :1529.6 - 1560.6 nm Span Length :100 km

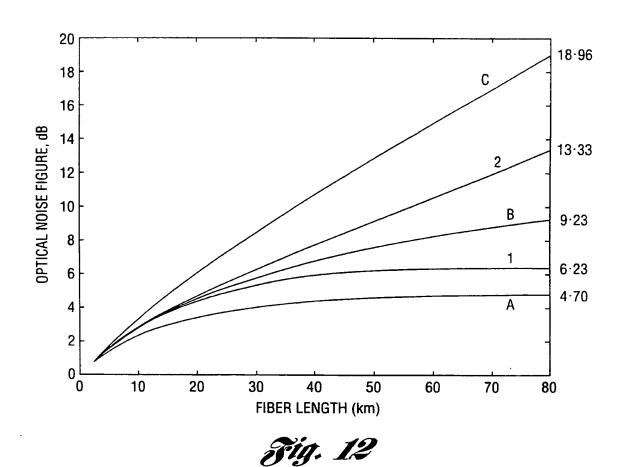
High band Ch. spacing :100GHz

:1570.4 - 1603.2 nm Linear loss :25 dB Mode field area :80 µm² Raman coeff. :4.4 x 10⁻¹⁴ m/W

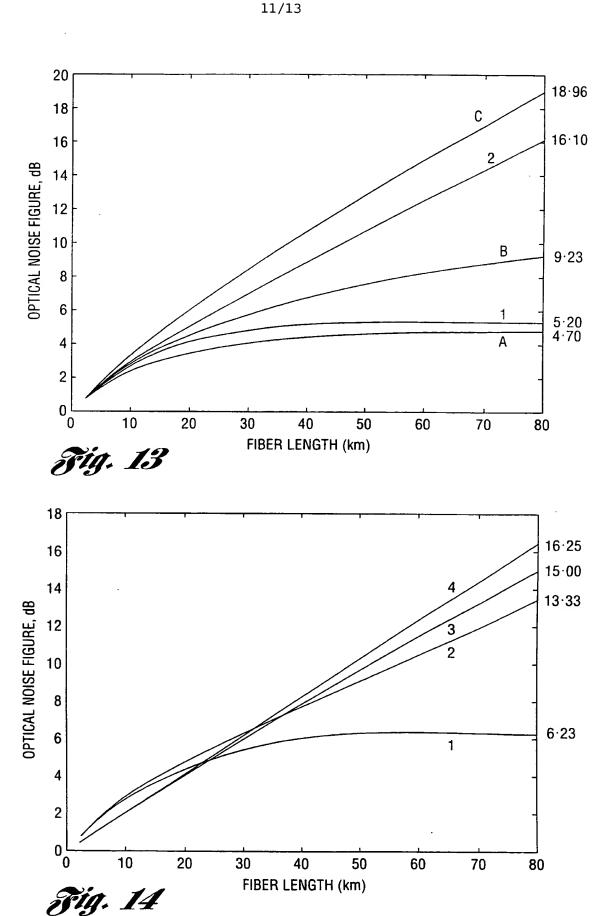


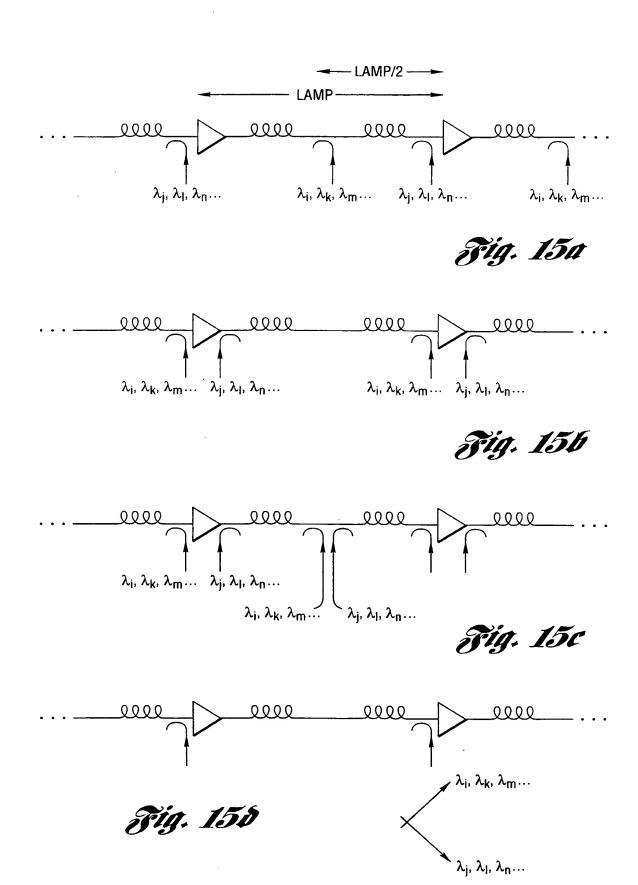
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